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FGA30N65SMD 650 V, 30 A Field Stop IGBT

Features

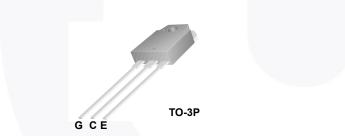
- Maximum Junction Temperature : T_J =175^oC
- Positive Temperaure Co-efficient for Easy Parallel Operating
- High Current Capability
- + Low Saturation Voltage: V_{CE(sat)} =1.98 V(Typ.) @ I_C = 30 A
- High Input Impedance
- Fast Switching
- Tighten Parameter Distribution
- RoHS Compliant

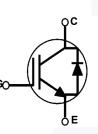
Applications

- Solar Inverter
- UPS, Welder, SMPS

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 2nd generation IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		650	V
V _{GES}	Gate to Emitter Voltage		± 20	V
I _C	Collector Current	@ T _C = 25°C	60	А
	Collector Current	@ T _C = 100 ^o C	30	А
I _{CM (1)}	Pulsed Collector Current		90	А
IF	Diode Forward Current	@ T _C = 25°C	40	A
'F	Diode Forward Current	@ T _C = 100 ^o C	20	A
I _{FM (1)}	Pulsed Diode Maximum Forward Current		120	A
P _D	Maximum Power Dissipation	@ T _C = 25°C	300	W
• D	Maximum Power Dissipation	@ T _C = 100 ^o C	150	W
TJ	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	°C
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

August 2014

Thermal Characteristics

Symbol	Parameter	Max.	Unit
R _{0JC} (IGBT)	Thermal Resistance, Junction to Case, Max.	0.5	°C/W
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case, Max.	1.5	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	40	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGA30N65SMD	FGA30N65SMD	TO-3P	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	V_{GE} = 0 V, I _C = 250 μ A	650	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage	V_{GE} = 0 V, I _C = 250 μ A	-	0.29	-	V/ºC
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA
I _{GES}	G-E Leakage Current	V_{GE} = V_{GES} , V_{CE} = 0 V	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 250 μA, V _{CE} = V _{GE}	3.5	4.8	6.0	V
- (- /		I _C = 30 A, V _{GE} = 15 V	-	1.98	2.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 30 A, V _{GE} = 15 V, T _C = 175 ^o C	-	2.29	-	V
Dynamic C	characteristics			7		
C _{ies}	Input Capacitance			1350	-	pF
C _{oes}	Output Capacitance	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz	-	130	-	pF
C _{res}	Reverse Transfer Capacitance		-	45	-	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time		-	14	-	ns
t _r	Rise Time		-	28	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 30 A,	-	102	-	ns
t _f	Fall Time	R _G = 6 Ω, V _{GE} = 15 V,	-	10	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	716	-	uJ
E _{off}	Turn-Off Switching Loss		-	208	-	uJ
E _{ts}	Total Switching Loss		-	924	-	uJ
t _{d(on)}	Turn-On Delay Time		-	13	-	ns
t _r	Rise Time]	-	28	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 30 A,	-	108	-	ns
t _f	Fall Time	R _G = 6 Ω, V _{GE} = 15 V,	-	17	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T _C = 175 ^o C	-	1125	-	uJ
E _{off}	Turn-Off Switching Loss]	-	572	-	uJ
E _{ts}	Total Switching Loss		-	1697	-	uJ

Electrical Characteristics of the IGBT (Continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Qg	Total Gate Charge		-	87	-	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 30 A, V _{GE} = 15 V	-	9.1	-	nC
Q _{gc}	Gate to Collector Charge	VGE - 10 V	-	45	-	nC

Electrical Characteristics of the Diode T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	ns	Min.	Тур.	Max	Unit
V _{FM}	Diode Forward Voltage	I _E = 20 A	T _C = 25°C	-	2.1	2.7	V
* FM	Blodo i olivara voltago		T _C = 175 ^o C	-	1.83	-	
E _{rec}	Reverse Recovery Energy		T _C = 175 ^o C	-	55	-	uJ
t.	Diode Reverse Recovery Time	I _F =20 A, di _F /dt = 200 A/μs	T _C = 25 ^o C	-	35	-	ns
۲ _{rr}		iε -20 Λ, αε/αι - 200 Λ/μ3	T _C = 175 ^o C	-	182	-	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25 ^o C	-	59	-	nC
- SII	Didde Horeice Hobevery endige		T _C = 175 ^o C	-	587	-	

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

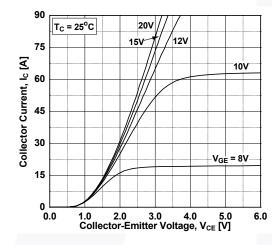


Figure 3. Typical Saturation Voltage Characteristics

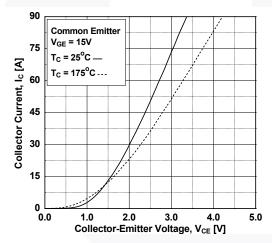


Figure 5. Saturation Voltage vs. V_{GE}

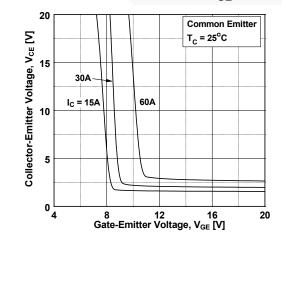
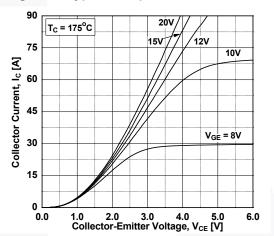
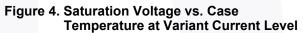
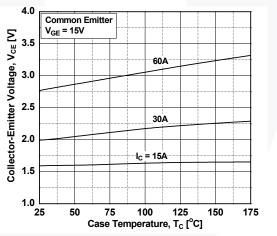


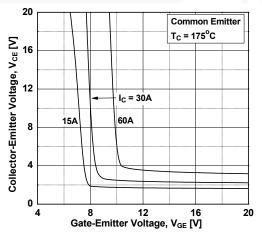
Figure 2. Typical Output Characteristics











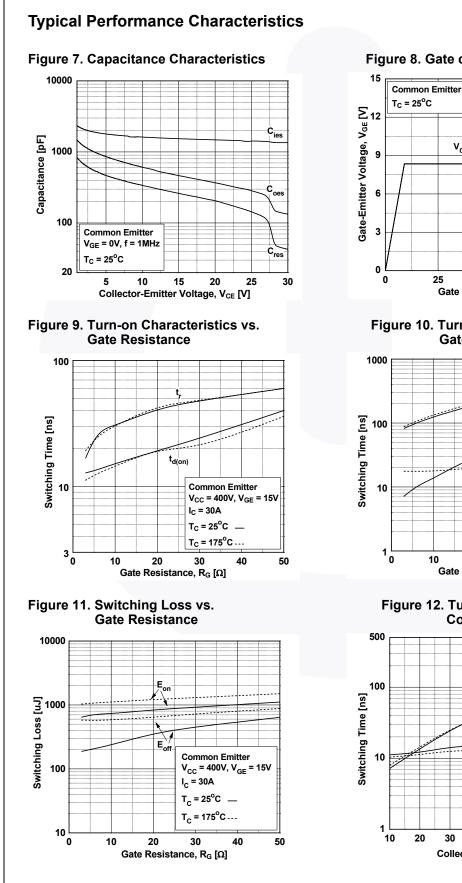
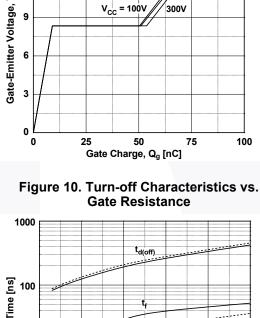


Figure 8. Gate charge Characteristics

200V





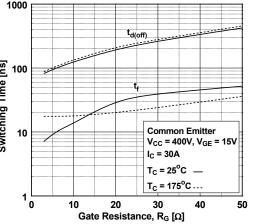
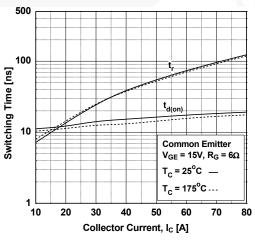


Figure 12. Turn-on Characteristics vs. **Collector Current**



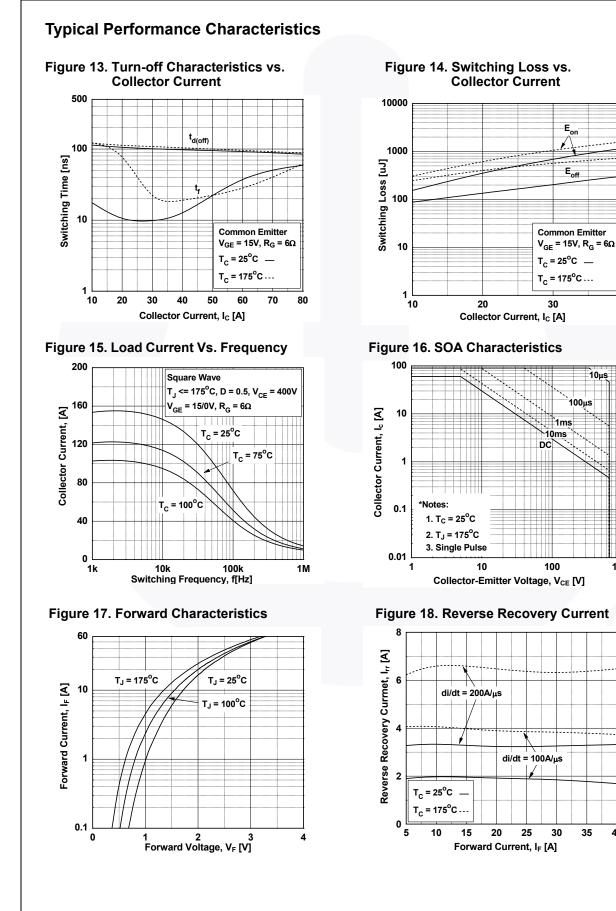
E_{off}

40

1000

10µs

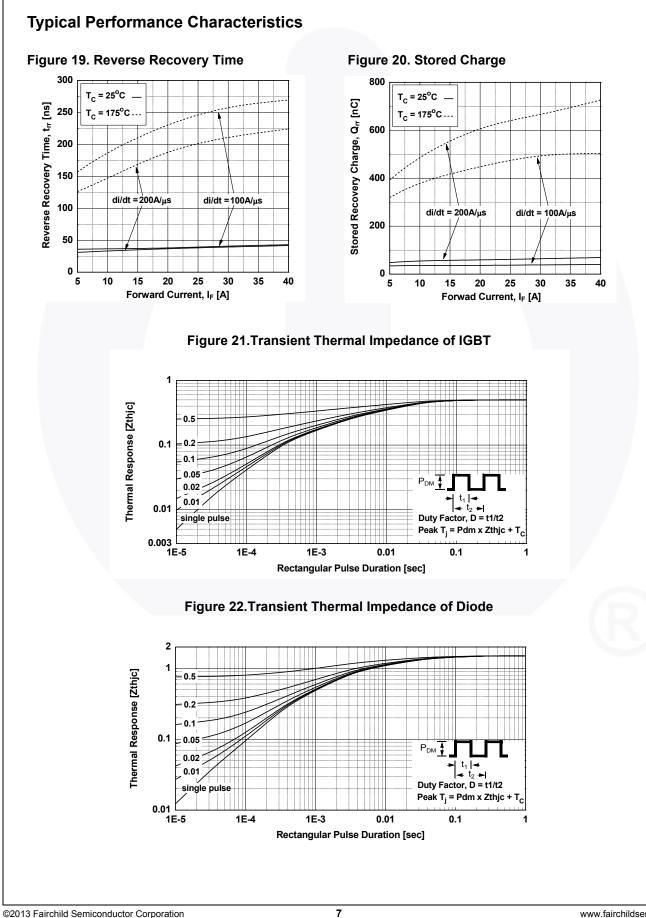
100µs

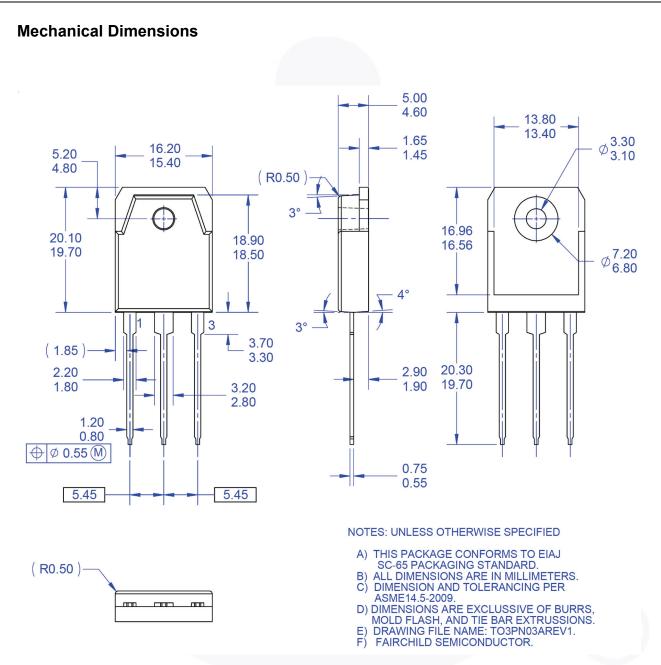


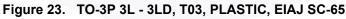
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